



SBOS161A – JANUARY 1989 – REVISED JULY 2003

Precision Dual *Difet*® Operational Amplifier

FEATURES

- Very Low Noise: $8\text{nV}/\sqrt{\text{Hz}}$ at 10kHz
- Low V_{OS} : 1mV max
- Low Drift: $10\mu\text{V}/^\circ\text{C}$ max
- Low I_B : 10pA max
- Fast Settling Time: 2 μs to 0.01%
- Unity-Gain Stable

APPLICATIONS

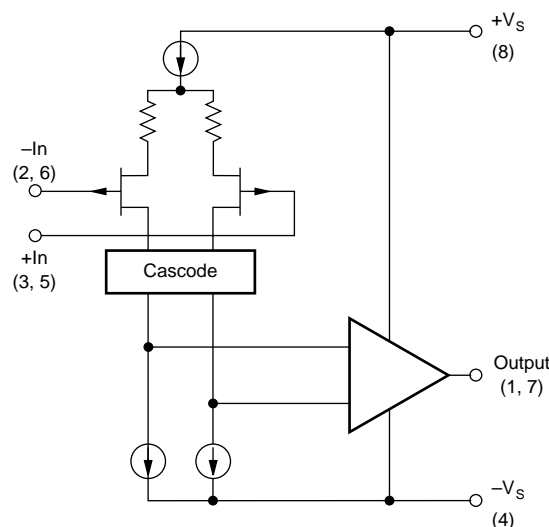
- Data Acquisition
- DAC Output Amplifiers
- Optoelectronics
- High-Impedance Sensor Amps
- High-Performance Audio Circuitry
- Medical Equipment, CT Scanners

DESCRIPTION

The OPA2107 dual operational amplifier provides precision *Difet* performance with the cost and space savings of a dual op amp. It is useful in a wide range of precision and low-noise analog circuitry and can be used to upgrade the performance of designs currently using BIFET® type amplifiers.

The OPA2107 is fabricated on a proprietary dielectrically isolated (*Difet*) process. This holds input bias currents to very low levels without sacrificing other important parameters, such as input offset voltage, drift and noise. Laser-trimmed input circuitry yields excellent dc performance. Superior dynamic performance is achieved, yet quiescent current is held to under 2.5mA per amplifier. The OPA2107 is unity-gain stable.

The OPA2107 is available in DIP-8 and SO-8 packages.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Supply Voltage	±18V
Input Voltage Range	±V _S ±2V
Differential Input Voltage	Total V _S ±4V
Operating Temperature	
P and U Packages	–25°C to + 85°C
Storage Temperature	
P and U Packages	–40°C to +125°C
Output Short Circuit to Ground (T _A = +25°C)	Continuous
Junction Temperature	+175°C
Lead Temperature	
P Package (soldering, 10s)	+300°C
U Package, SOIC (3s)	+260°C

NOTE: Stresses above these ratings may cause permanent damage.

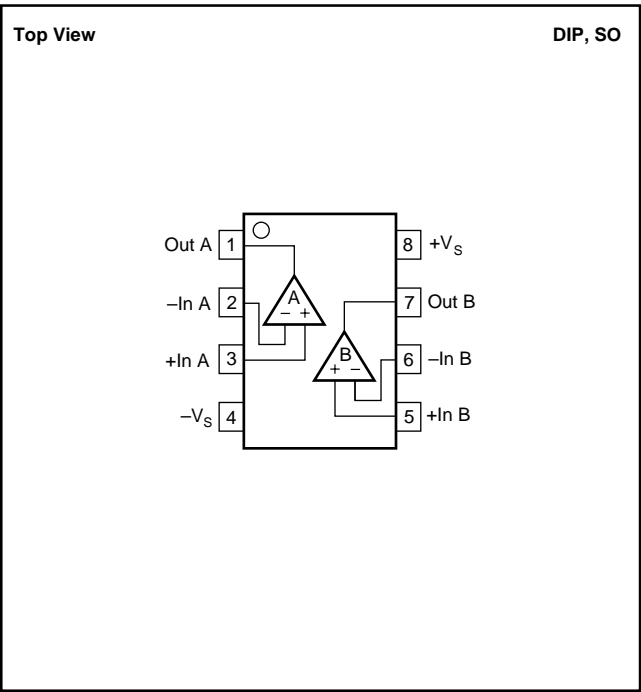


ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PIN CONFIGURATION



PACKAGE/ORDERING INFORMATION

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR ⁽¹⁾	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
OPA2107	DIP-8	P	–25°C to +85°C	OPA2107AP	OPA2107AP	Tube, 50
OPA2107	SO-8	D	–25°C to +85°C	OPA2107AU	OPA2107AU	Tube, 100
"	"	"	"	"	OPA2107AU/2K5	Tape and Reel, 2500

NOTE: (1) For the most current specifications and package information, refer to our web site at www.ti.com.

ELECTRICAL CHARACTERISTICS

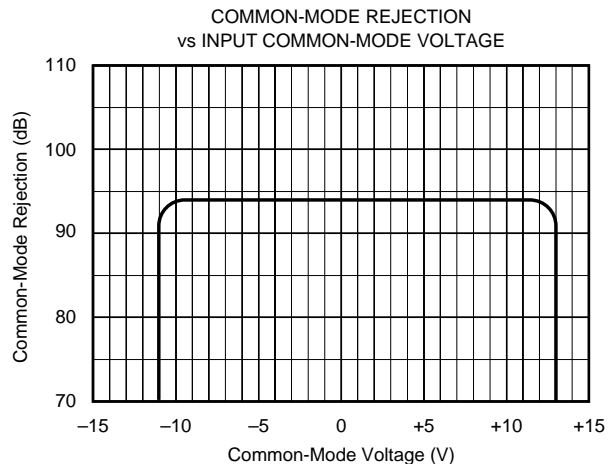
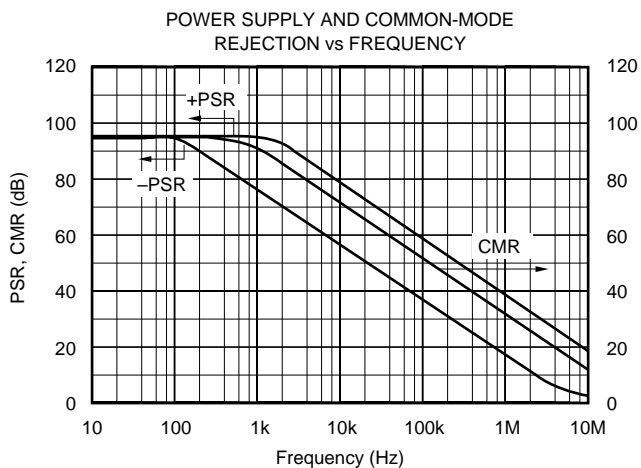
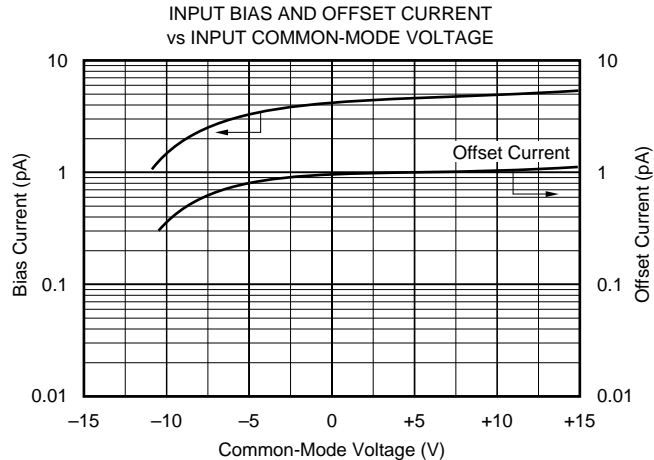
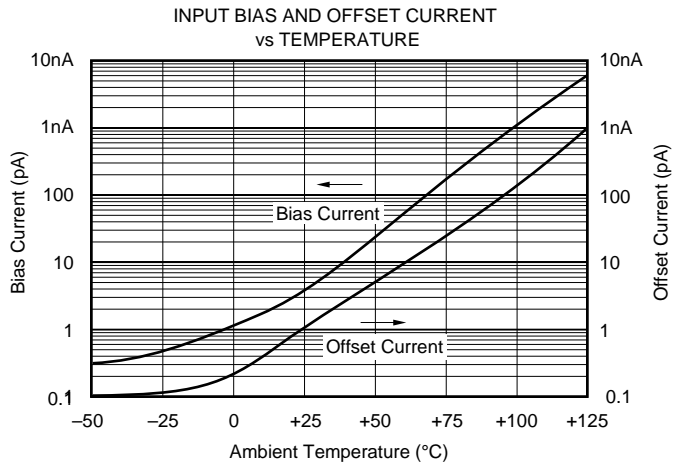
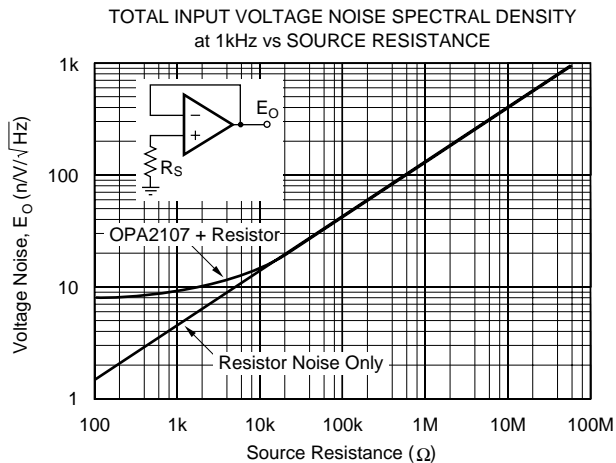
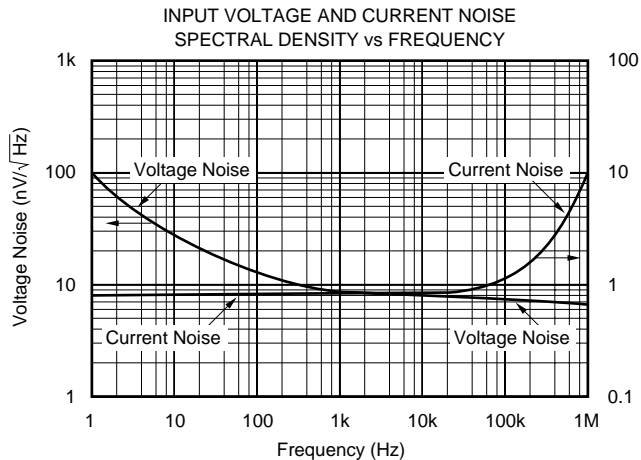
At $T_A = +25^\circ\text{C}$, $V_S = \pm 15\text{V}$, unless otherwise noted.

PARAMETER	CONDITION	OPA2107AP, AU			UNITS
		MIN	TYP	MAX	
OFFSET VOLTAGE⁽¹⁾ Input Offset Voltage Over Specified Temperature Average Drift Over Specified Temperature Power Supply Rejection	$V_{CM} = 0\text{V}$ $V_S = \pm 10$ to $\pm 18\text{V}$	 80	0.1 0.5 3 96	1 2 10	mV mV $\mu\text{V}/^\circ\text{C}$ dB
INPUT BIAS CURRENT⁽¹⁾ Input Bias Current Over Specified Temperature Input Offset Current Over Specified Temperature	$V_{CM} = 0\text{V}$ $V_{CM} = 0\text{V}$		4 0.25 1	10 1.5 8 1	pA nA pA nA
INPUT NOISE Voltage: $f = 10\text{Hz}$ $f = 100\text{Hz}$ $f = 1\text{kHz}$ $f = 10\text{kHz}$ $\text{BW} = 0.1$ to 10Hz $\text{BW} = 10$ to 10kHz Current: $f = 0.1\text{Hz}$ thru 20kHz $\text{BW} = 0.1\text{Hz}$ to 10Hz	$R_S = 0$		30 12 9 8 1.2 0.85 1.2 23		$\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$ $\mu\text{Vp-p}$ μVrms $\text{fA}/\sqrt{\text{Hz}}$ fAp-p
INPUT IMPEDANCE Differential Common-Mode			$10^{13} \parallel 2$ $10^{14} \parallel 4$		$\Omega \parallel \text{pF}$ $\Omega \parallel \text{pF}$
INPUT VOLTAGE RANGE Common-Mode Input Range Over Specified Temperature Common-Mode Rejection	$V_{CM} = \pm 10\text{V}$	± 10.5 ± 10.2 80	± 11 ± 10.5 94		V V dB
OPEN-LOOP GAIN Open-Loop Voltage Gain Over Specified Temperature	$V_O = \pm 10\text{V}$, $R_L = 2\text{k}\Omega$	82 80	96 94		dB dB
DYNAMIC RESPONSE Slew Rate Settling Time: 0.1% 0.01% Gain Bandwidth Product THD + Noise Channel Separation	$G = +1$ $G = -1$, 10V Step $G = 100$ $G = +1$, $f = 1\text{kHz}$ $f = 100\text{Hz}$, $R_L = 2\text{k}\Omega$	13	18 1.5 2 4.5 0.001 120		V/ μs μs μs MHz % dB
POWER SUPPLY Specified Operating Voltage Operating Voltage Range Current		± 4.5	± 15 ± 4.5		V V mA
OUTPUT Voltage Output Over Specified Temperature Short Circuit Current Output Resistance, Open-Loop Capacitive Load Stability	$R_L = 2\text{k}\Omega$ 1MHz $G = +1$	± 11 ± 10.5 ± 10	± 12 ± 11.5 ± 40 70 1000		V V mA Ω pF
TEMPERATURE RANGE Specification Operating Storage Thermal Resistance (θ_{JA}) DIP-8 SO-8		-25 -25 -40		+85 +85 +125	$^\circ\text{C}$ $^\circ\text{C}$ $^\circ\text{C}$ $^\circ\text{C}/\text{W}$ $^\circ\text{C}/\text{W}$ $^\circ\text{C}/\text{W}$

NOTE: (1) Specified with devices fully warmed up.

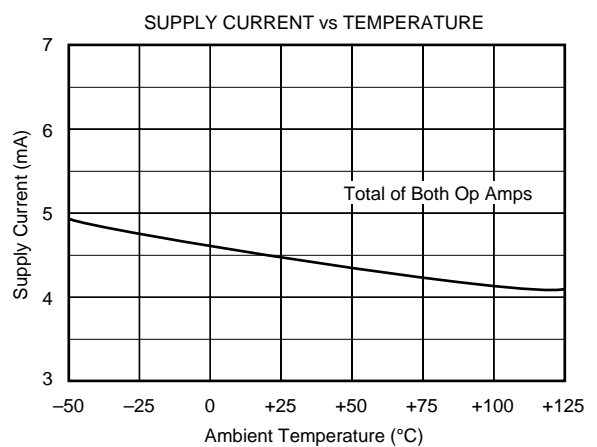
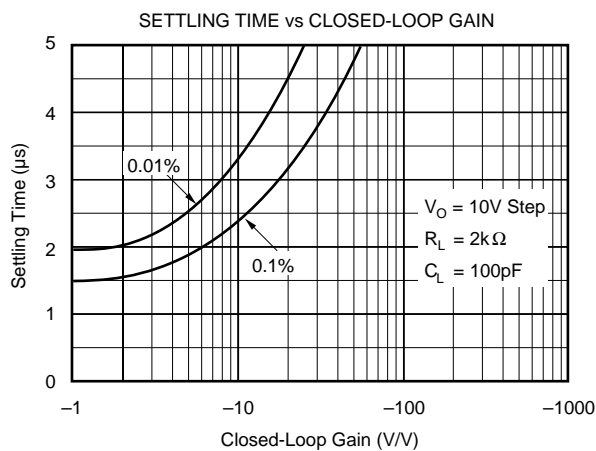
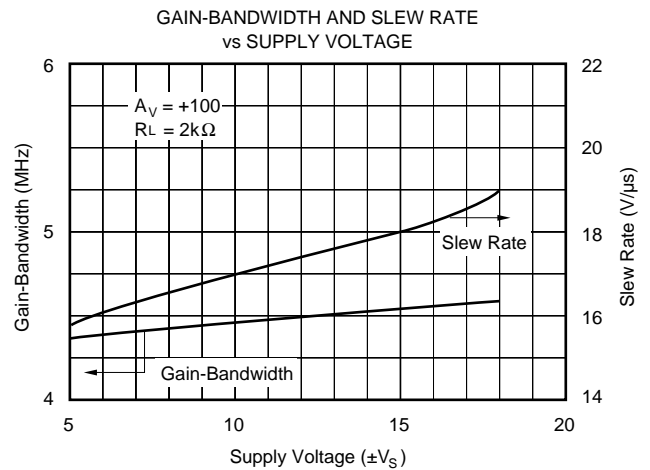
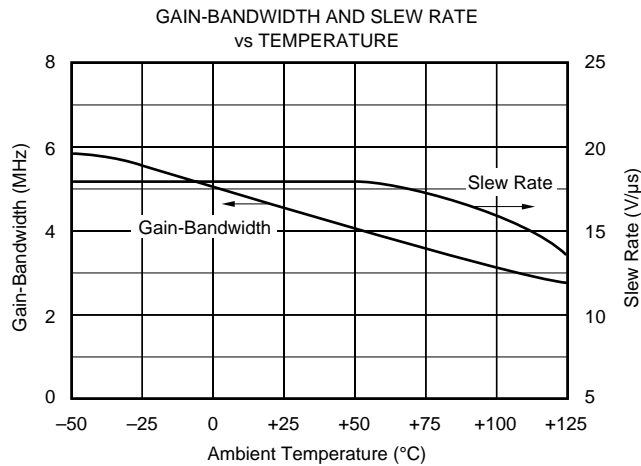
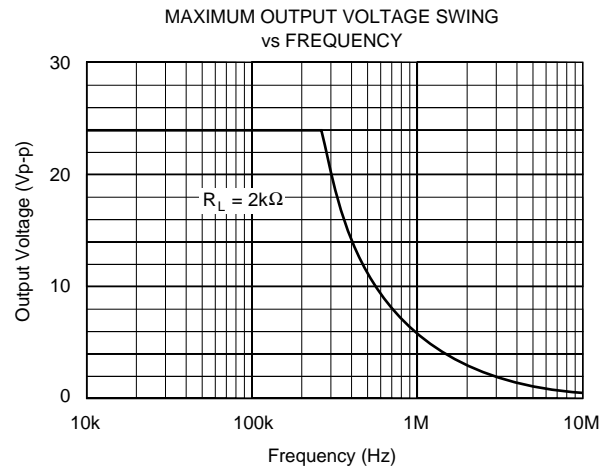
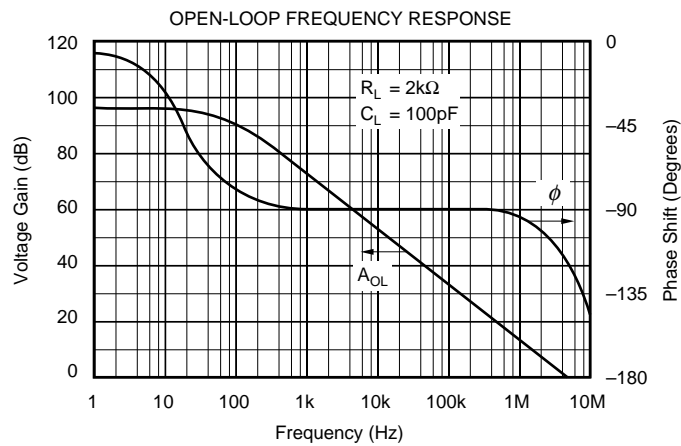
TYPICAL CHARACTERISTICS

$T_A = +25^\circ\text{C}$, $V_S = \pm 15\text{V}$ unless otherwise noted.



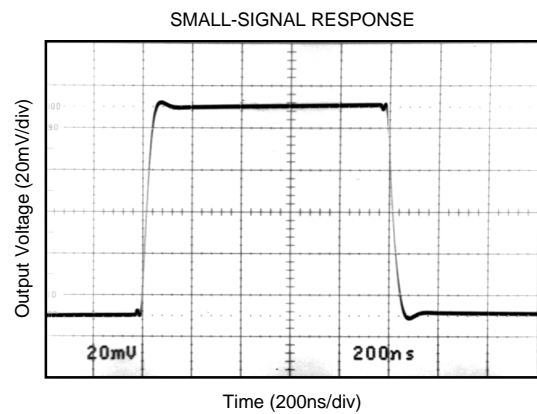
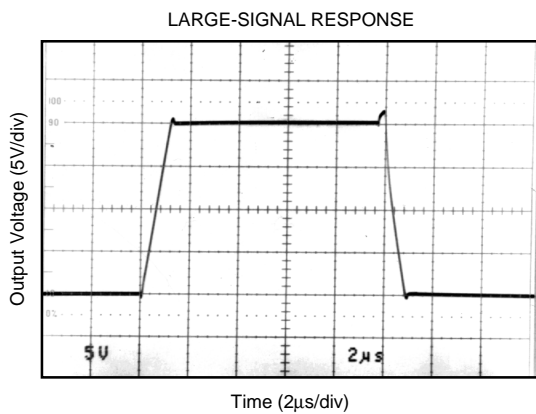
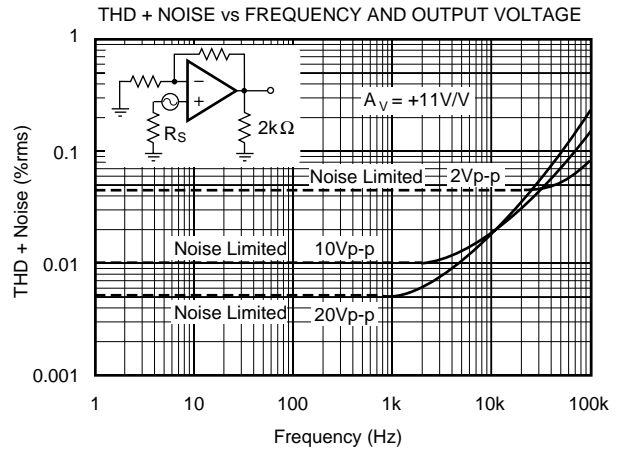
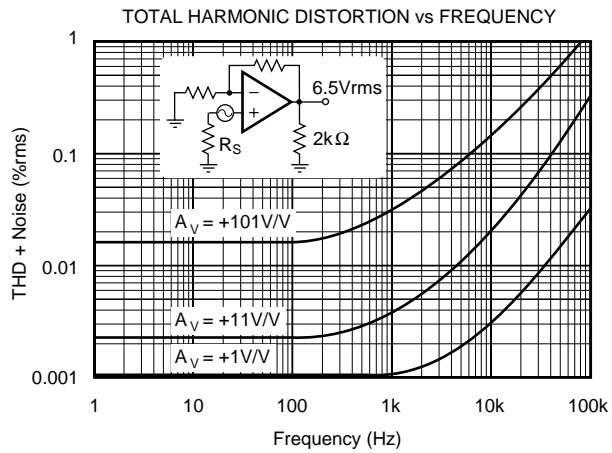
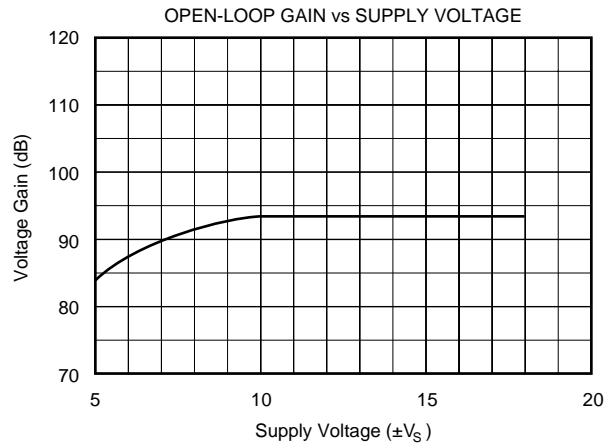
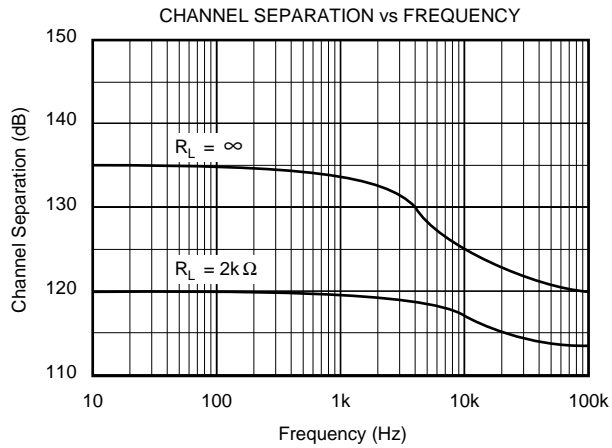
TYPICAL CHARACTERISTICS (Cont.)

$T_A = +25^\circ\text{C}$, $V_S = \pm 15\text{V}$ unless otherwise noted.



TYPICAL CHARACTERISTICS (Cont.)

$T_A = +25^\circ\text{C}$, $V_S = \pm 15\text{V}$ unless otherwise noted.



APPLICATIONS INFORMATION AND CIRCUITS

The OPA2107 is unity-gain stable and has an excellent phase margin. This makes it easy to use in a wide variety of applications.

Power-supply connections should be bypassed with capacitors positioned close to the amplifier pins. In most cases, 0.1µF ceramic capacitors are adequate. Applications with larger load currents and fast transient signals may need up to 1µF tantalum bypass capacitors.

INPUT BIAS CURRENT

The OPA2107 *Difet* input stages have very low input bias current—an order of magnitude lower than BIFET op amps. Circuit-board leakage paths can significantly degrade performance. This is especially evident with the SO-8 surface-mount package where pin-to-pin dimensions are particularly small. Residual soldering flux, dirt, and oils, which conduct leakage current, can be removed by proper cleaning. In most instances, a two-step cleaning process is adequate using a clean organic solvent rinse followed by deionized water. Each rinse should be followed by a 30-minute bake at 85°C. A circuit-board guard pattern effectively reduces errors due to circuit-board leakage (Figure 1). By encircling critical high-impedance nodes with a low-impedance connection at the same circuit potential, any leakage currents will flow harmlessly to the low-impedance node. Guard traces should be placed on all levels of a multiple-layer circuit board.

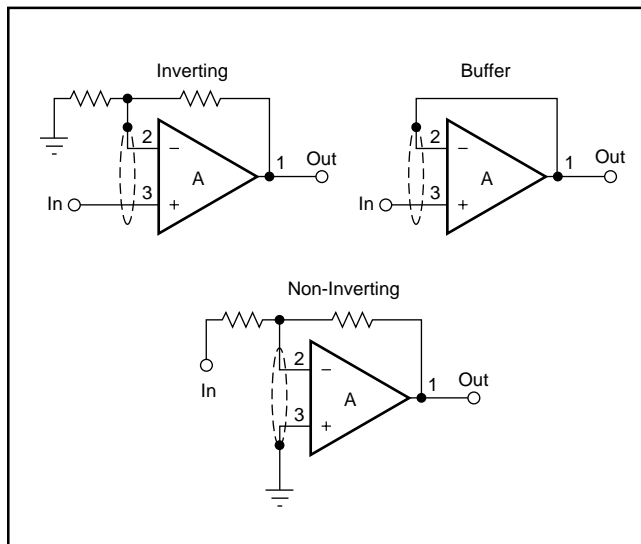


FIGURE 1. Connection of Input Guard.

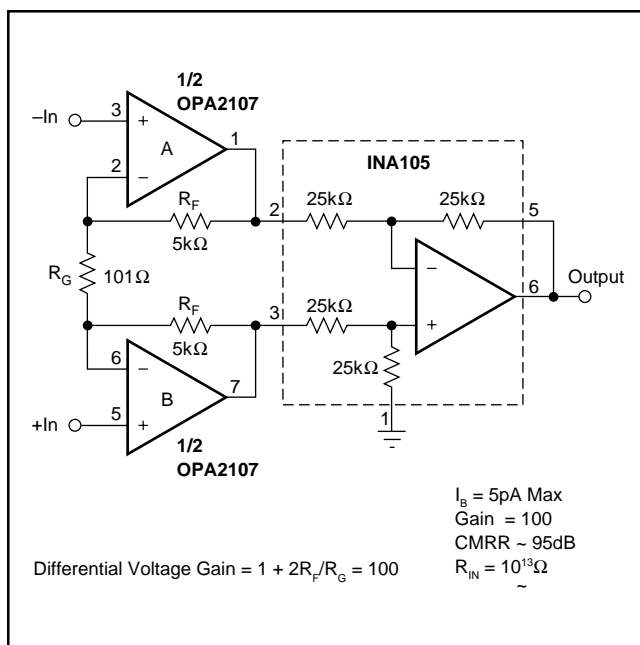


FIGURE 2. FET Input Instrumentation Amplifier.

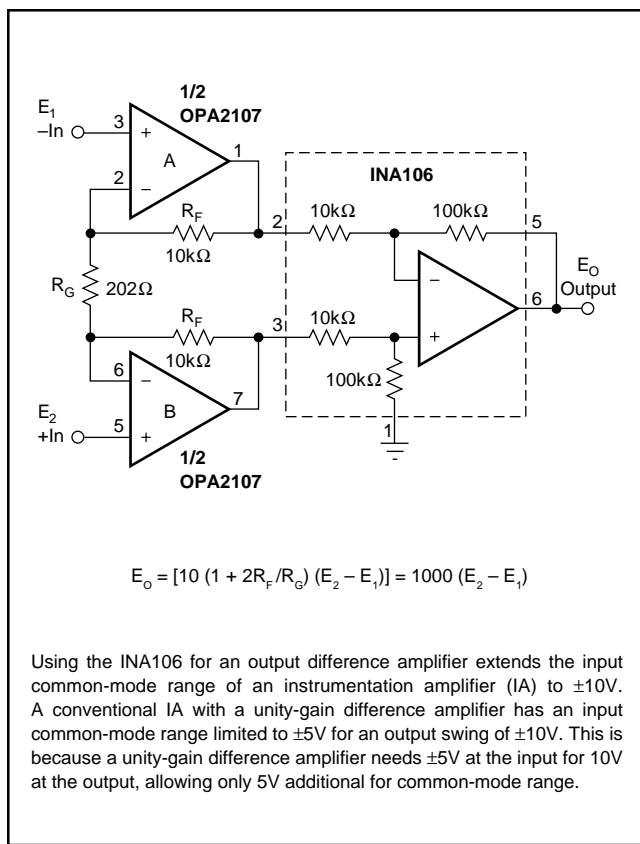


FIGURE 3. Precision Instrumentation Amplifier.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
OPA2107AP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	Call TI	Level-NC-NC-NC
OPA2107AU	ACTIVE	SOIC	D	8	100	None	CU SNPB	Level-3-220C-168 HR
OPA2107AU/2K5	ACTIVE	SOIC	D	8	2500	None	CU SNPB	Level-3-220C-168 HR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - May not be currently available - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

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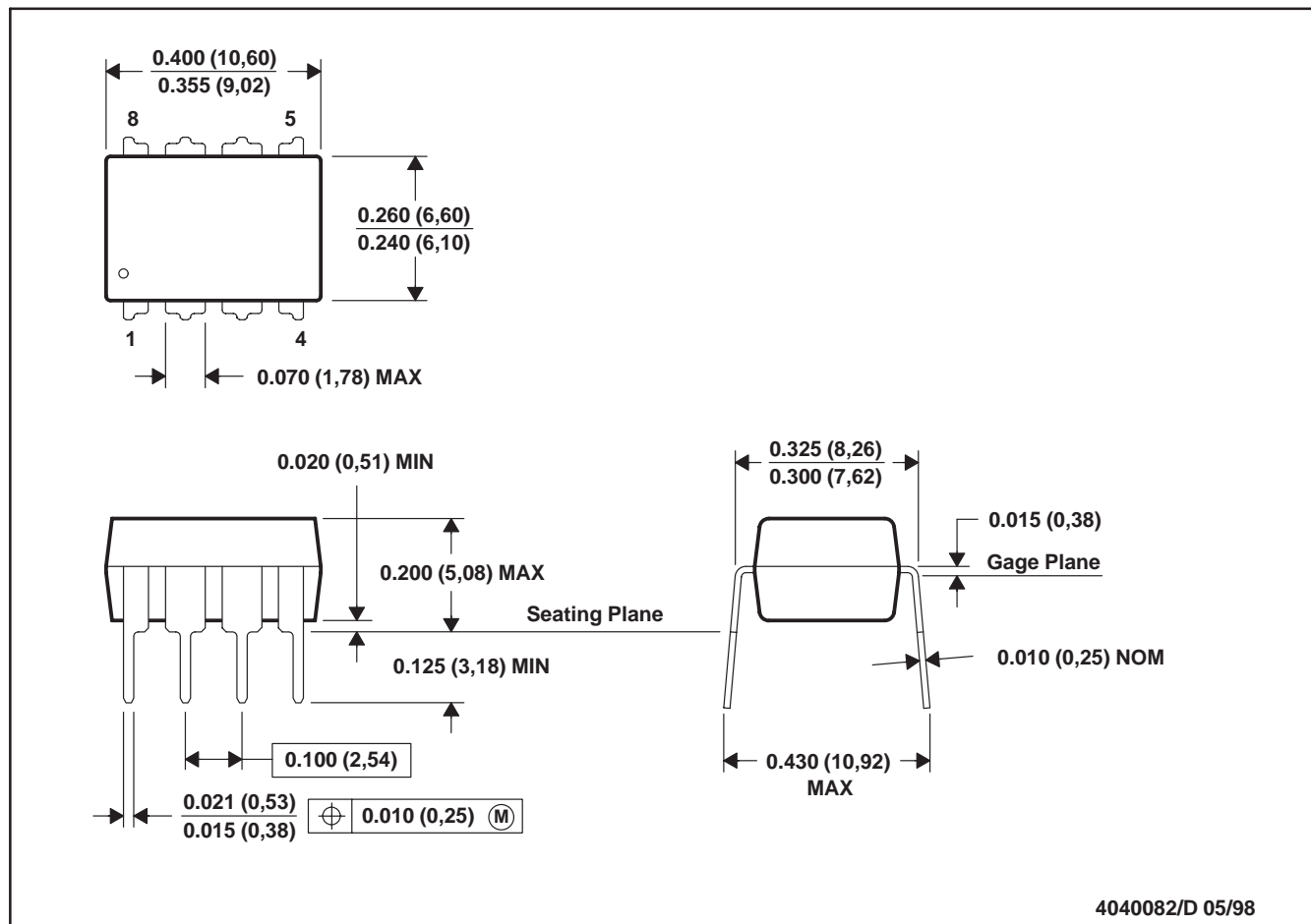
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001

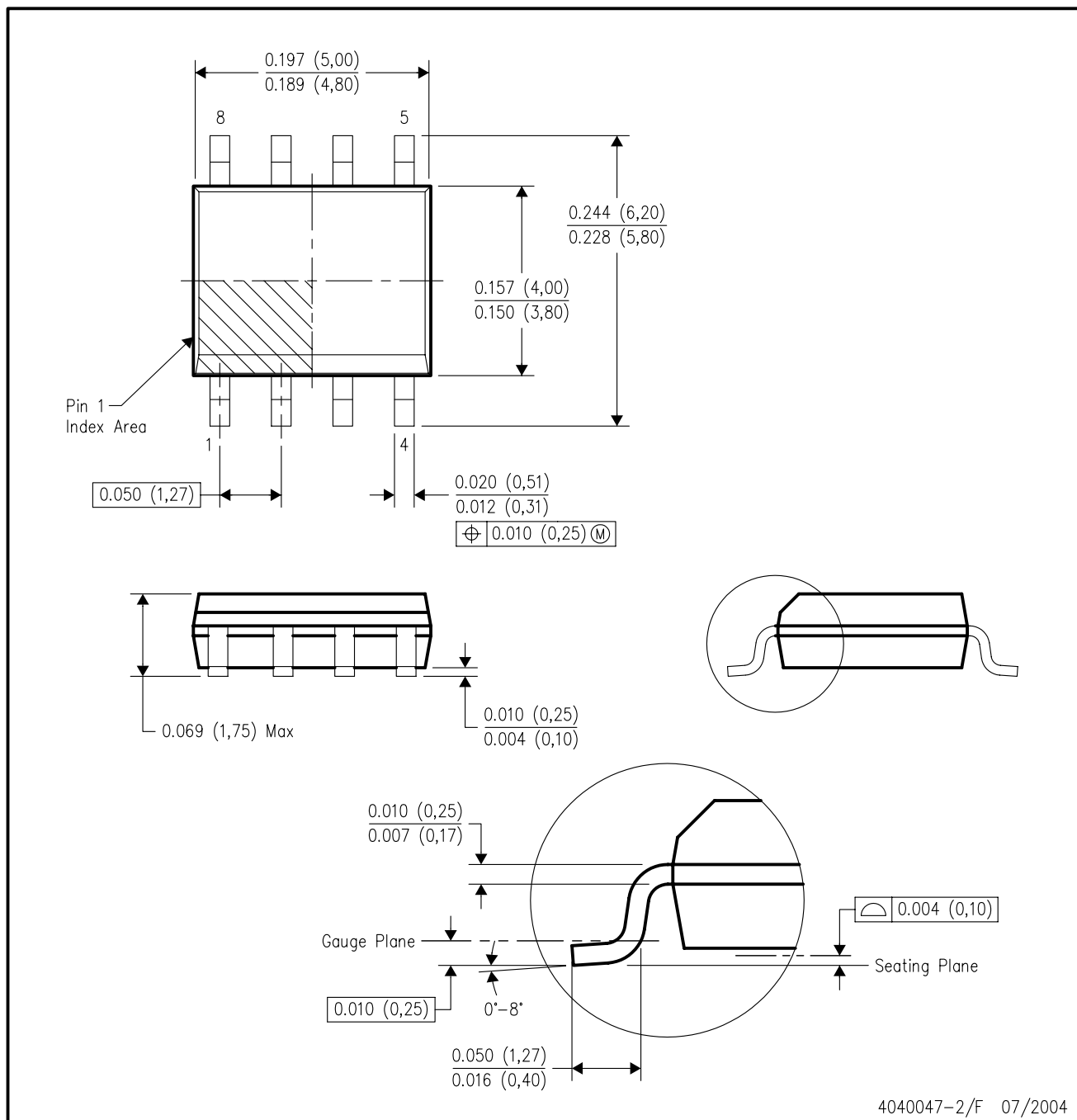
For the latest package information, go to http://www.ti.com/sc/docs/package/pkg_info.htm



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D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - Falls within JEDEC MS-012 variation AA.

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